Tablet Device

Solution Proposal by Toshiba









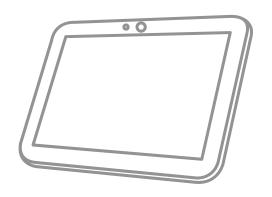




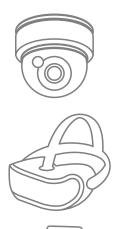








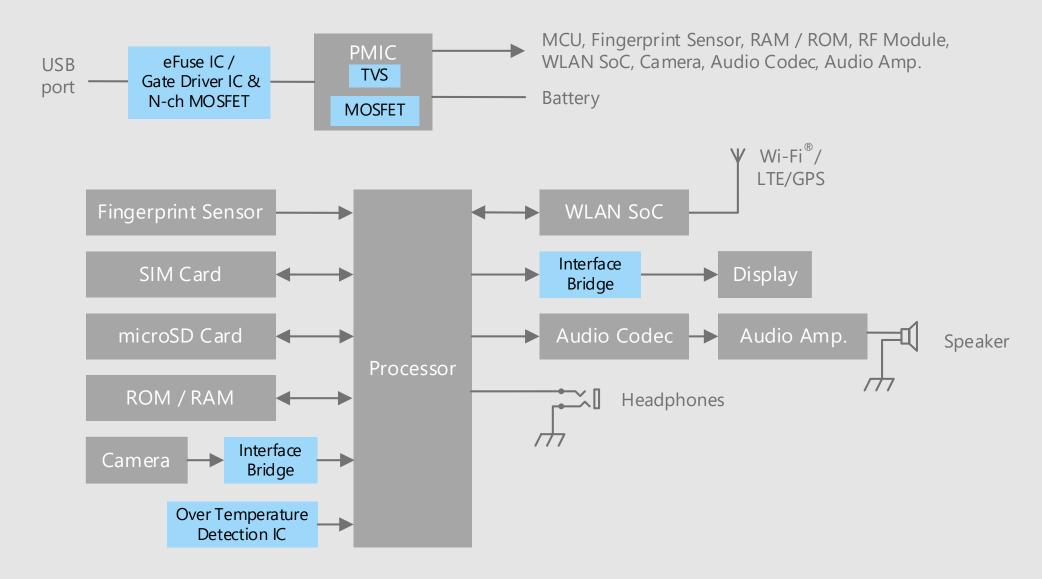
Toshiba Electronic Devices & Storage Corporation provides comprehensive device solutions to customers developing new products by applying its thorough understanding of the systems acquired through the analysis of basic product designs.



Block Diagram

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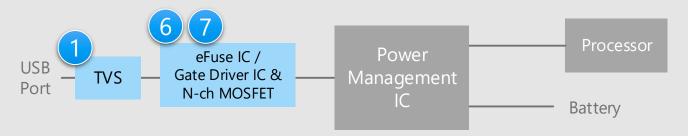
Tablet Device Overall block diagram



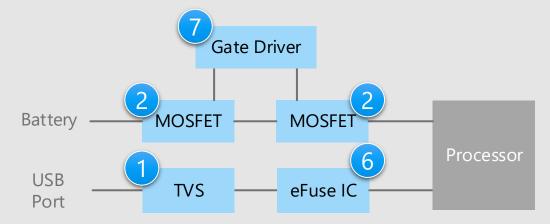
Tablet Device Details of power supply unit

System power circuit

Method using power controller



Method without power controller



* Click on the blue circled numbers above to view detailed descriptions.

Criteria for device selection

- TVS diodes are suitable for ESD protection of power line.
- MOSFETs with low on-resistance are suitable for the control of USB and battery powered supply circuits.
- Small package products contribute to the reduction of circuit board area.

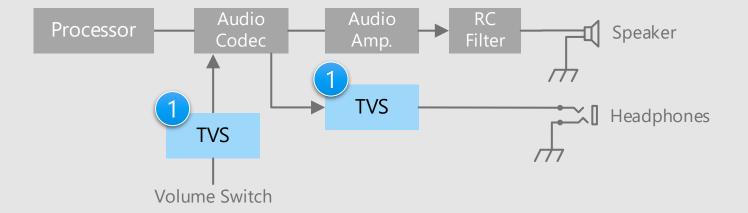
- Prevent circuit malfunctions by absorbing static electricity from external terminals TVS diode
- Realize the set with low power consumption by low on-resistance
 Small signal MOSFET
- Built-in protection function against short circuit, over current, over voltage, etc.
 Electronic fuse (eFuse IC)
- Small package and built-in over voltage protection function
 N-ch MOSFET gate driver IC





Tablet Device Detail of audio unit

Audio unit circuit



Criteria for device selection

- TVS diodes are suitable for ESD protection of signal line.
- Small package products contribute to the reduction of circuit board area.

Proposal from Toshiba

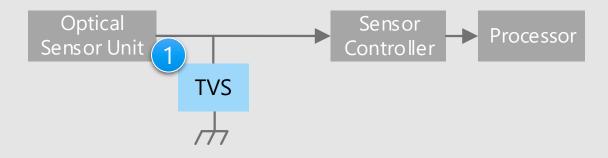
 Prevent circuit malfunctions by absorbing static electricity from external terminals TVS diode

^{*} Click on the blue circled numbers above to view detailed descriptions.

Tablet Device Details of touch sensor unit

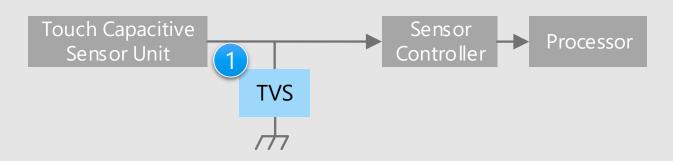
Touch sensor circuit

Optical type



Touch sensor circuit

Capacitive type



* Click on the blue circled numbers above to view detailed descriptions.

Criteria for device selection

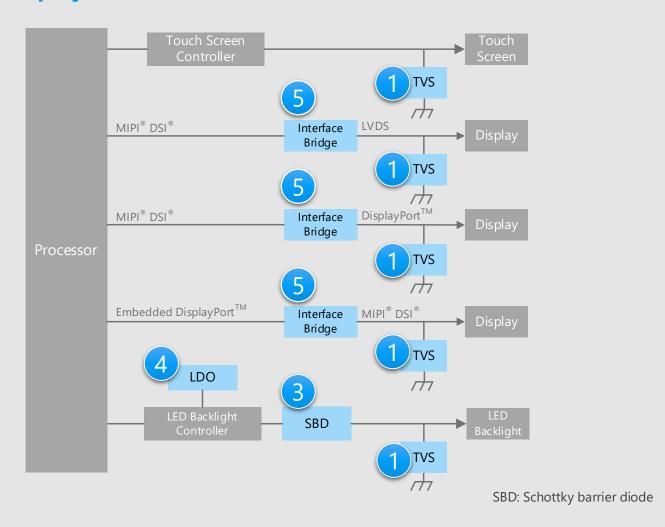
- TVS diodes are suitable for ESD protection of signal line.
- Small package products contribute to the reduction of circuit board area.

Proposal from Toshiba

Prevent circuit malfunctions by absorbing static electricity from external terminals
 TVS diode

Tablet Device Detail of display unit

Display unit circuit



^{*} Click on the blue circled numbers above to view detailed descriptions.

Criteria for device selection

- TVS diodes are suitable for ESD protection of signal line.
- By using a Schottky barrier diode with low V_F and low I_R , the power consumption of the set can be reduced.
- Small package products contribute to the reduction of circuit board area.
- By using interface bridge, display and camera components can be selected without any concern for interface standards.

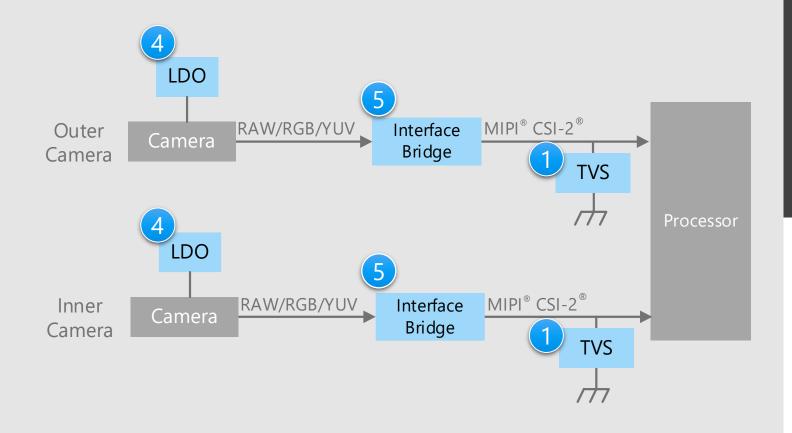
- Prevent circuit malfunctions by absorbing static electricity from external terminals

 TVS diode
- High speed, low loss
 Schottky barrier diode
- Supply the power with low noise
 Small surface mount LDO regulator
- Eliminate differences between interfaces
 Interface bridge

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Tablet Device Detail of camera unit

Camera unit circuit



Criteria for device selection

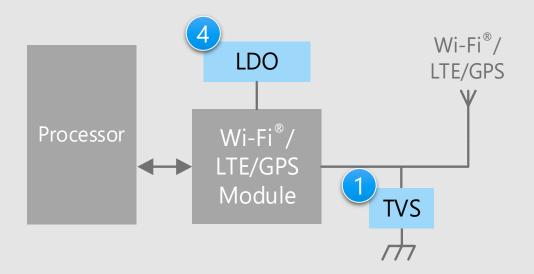
- PSRR (Power Supply Rejection Ratio) of LDO regulator is an important parameter for camera modules.
- TVS diodes are suitable for ESD protection of signal line.
- Small package products contribute to the reduction of circuit board area.
- By using interface bridge, display and camera components can be selected without any concern for interface standards.

- Prevent circuit malfunctions by absorbing static electricity from external terminals
 TVS diode
- Supply the power with low noise Small surface mount LDO regulator
- Eliminate differences between interfaces
 Interface bridge

^{*} Click on the blue circled numbers above to view detailed descriptions.

Tablet Device Detail of wireless unit

Wireless communication circuit



Criteria for device selection

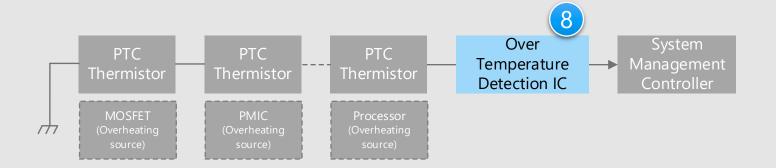
- Small package products contribute to the reduction of circuit board area.
- A small TVS diode with low C_t is suitable for ESD protection without attenuating the antenna signal.
- LDO regulator that can supply large current is suitable for the wireless module.

- Prevent circuit malfunctions by absorbing static electricity from external terminals
 TVS diode
- Supply the power with low noise Small surface mount LDO regulator

^{*} Click on the blue circled numbers above to view detailed descriptions.

Tablet Device Detail of over temperature monitoring unit

Over temperature monitoring circuit



Criteria for device selection

- Over temperature monitoring is required at multiple points on the circuit board such as MOSFET, PMIC and Processor.
- Low power dissipation of set can be realized by using the over temperature detection IC with low current consumption.
- Small package products contribute to the reduction of circuit board area.

Proposal from Toshiba

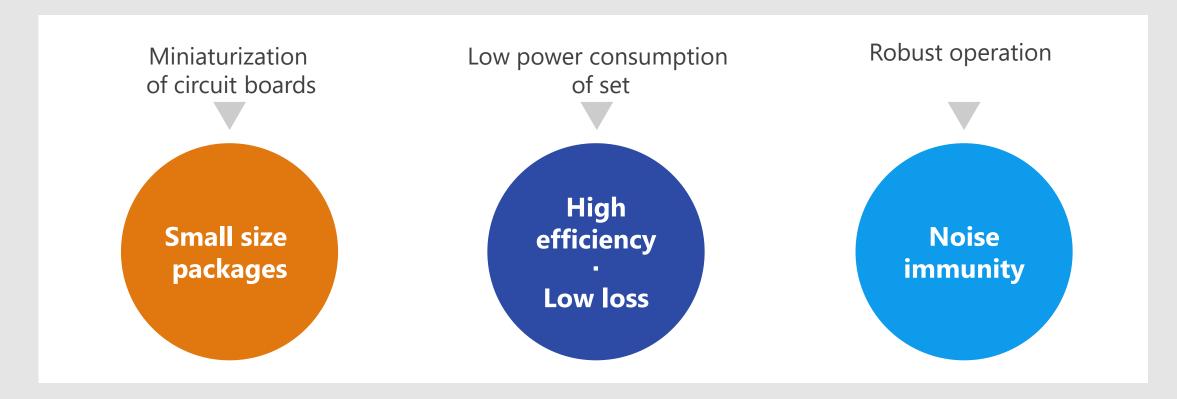
 Monitor temperature at multiple points with small package and low current consumption
 Over temperature detection IC (ThermoflaggerTM)

^{*} Click on the blue circled numbers above to view detailed descriptions.

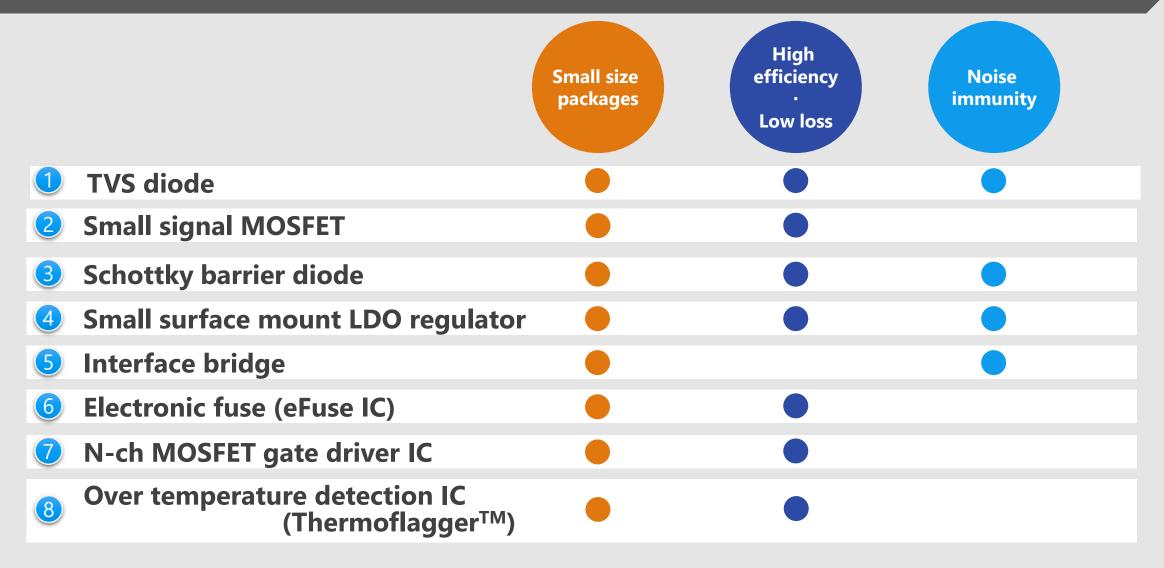


Device solutions to address customer needs

As described above, in the design of tablet device, "Miniaturization of circuit boards", "Low power consumption of set" and "Robust operation" are important factors. Toshiba's proposals are based on these three solution perspectives.



Device solutions to address customer needs









Absorbs static electricity from external terminals, prevents circuit malfunction and protects devices.

Improved ESD pulse absorption

Improved ESD absorption compared to our conventional products. (50 % reduction in operating resistance) For some products, both low operating resistance and low capacitance are realized and ensures high signal protection performance and signal quality.

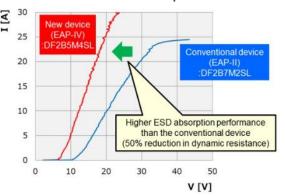
Suppress ESD energy by low clamp voltage

Protect the connected circuits/devices using proprietary technology.

Suitable for high density mounting

A variety of small packages are available.

ESD Pulse Absorption Performance Toshiba internal comparison



Unidirectional



Suitable for paths such as logic signals. There is lineups of 1in1, 2in1, 4in1, 5in1, 7in1.

Bidirectional



Suitable for paths with both polar signals such as audio signals

Lineup					
Part number	DF2B7ASL	DF2S14P2CTC	DF2B5M4ASL	DF2B6M4ASL	DF2B6M4BSL
Package	SL2	CST2C	SL2	SL2	SL2
V _{ESD} [kV]	±30	±30	±16	±15	±8
V _{RWM} (Max) [V]	5.5	12.6	3.6	5.5	5.5
C _t (Typ.) [pF]	8.5	270	0.15	0.15	0.12
R_{DYN} (Typ.) [Ω]	0.2	0.08	0.7	0.7	1.05

(Note) This product is designed for ESD protection purpose and cannot be used for purposes other than ESD protection.







Suitable for power management and contributes to miniaturization.

Low voltage operation

Operates down to $|V_{GS}| = 4.5 \text{ V}$

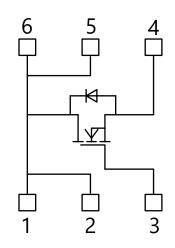
DescriptionLow on-resistance

By reducing on-resistance between the drain and source, heat generation and power consumption can be kept low.

3 Small package

Sealed in SOT-1220 (2.0 x 2.0 mm) package.

Internal circuit SSM6K513NU



Lineup								
Part numl	oer	SSM6K513NU		SSM6N55NU		SSM6J507NU		
Package	Э	UDFN6B (SOT-1220)	>	UDFN6 (SOT-1118)	The state of the s	UDFN6B (SOT-1220)	>	
Polarity	′	N-ch		N-ch	x 2	P-ch	ı	
V _{DSS} [V]		30		30		-30		
I _D [A]		15		4		-10		
$R_{DS(ON)}$ [m Ω]	Тур.	8.0		48		19		
$@ V_{GS} = 4.5 \text{ V}$	Max	12		64		28		

Schottky barrier diode CUHS20F40 / CTS05F40







Value provided

Can be applied to various applications which requires high speed and low loss, and contributes to miniaturization.

Fast switching

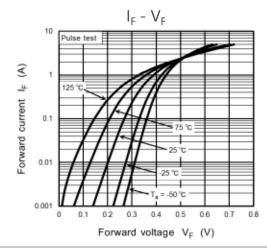
For fast switching applications.

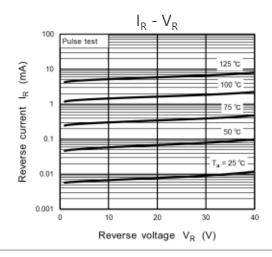
Small package

Small surface mount packages for high density assembly:

US2H: 2.5 x 1.4 x 0.6 mm CST2: 1.0 x 0.6 x 0.38 mm

CUHS20F40 Characteristics Curves





Lineup							
Part number	CUHS20F40	CTS05F40					
Package	US2H	CST2 0.5					
I _O [A]	2.0						
V _R [V]	40	40					
V _F (Typ.) [V]	0.39 @I _F = 1.0 A	0.74 @I _F = 0.5 A					
I _R (Max) [μΑ] @V _R = 40 V	60	15					







Wide lineup from general purpose type to small package type are provided. Contribute to realize a stable power supply not affected by fluctuation of battery.

Low dropout voltage

The originally developed latest process significantly improved the dropout voltage characteristics.

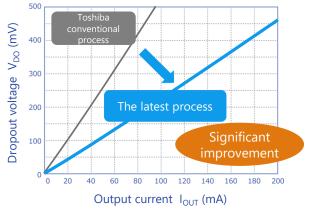
High PSRR Low output noise voltage

Many product series that realize both high PSRR (Power Supply Rejection Ratio) and low output noise voltage characteristics are provided. They are suitable for stable power supply for analog circuit.

3 Low current consumption

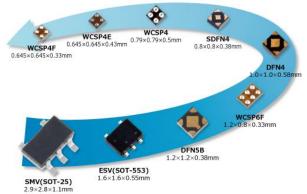
 $0.34~\mu A$ of $I_{B(ON)}$ is realized by utilizing CMOS process and unique circuit technology. (TCR3U Series)

Low dropout voltage



(Note) Toshiba internal comparison with TCR3U series.

Rich package lineup



Lineup									
Part number	TCR15AG Series	TCR13AG Series	TCR8BM Series	TCR5BM Series	TCR5RG Series	TCR3RM Series	TCR3U Series	TCR2L Series	TAR5 Series
Features		Low dropo High	out voltage PSRR		Low Low c	PSRR noise urrent mption		urrent mption	15 V Input voltage Bipolar type
I _{OUT} (Max) [A]	1.5	1.3	0.8	0	.5	0.	.3		0.2
PSRR (Typ.) [dB] @f = 1 kHz	95	90	98	98	100	100	70	-	70
I _B (Typ.) [μΑ]	25	56	20	19	7	7	0.34	1	170







Eliminating the interface gap between host and display/camera allows more options of component selection.

Wider component selection

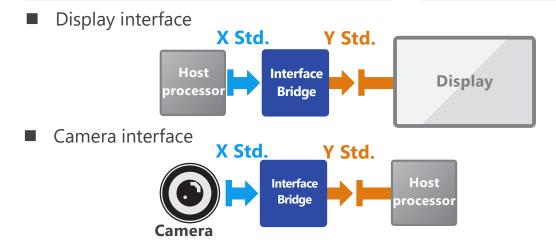
Conversion of the interface allows shared procurement with other products as well as adoption of less inexpensive parts.

Noise immunity

Converting parallel communication to serial improves noise immunity and suppresses noise generation to the surroundings.

3 Less cabling

Converting from parallel communication to serial reduces total number of wires and the risks of wire breakage.



Lineup							
Part number	TC358775XBG	TC358767AXBG	TC358860XBG	TC358746AXBG			
Package	BGA64	BGA81	BGA65	BGA72			
Input	MIPI [®] DSI [®] 1.01	(1) MIPI [®] DSI [®] 1.01 (2) MIPI [®] DPI SM 2.0	VESA Embedded DisplayPort™ (eDP)	(1) MIPI® CSI-2® (2) Parallel 24bit			
Output	LVDS Dual Link (5 pairs / link)	VESA DisplayPort™ 1.1a	MIPI [®] DSI [®] 1.02	(1) Parallel 24bit (2) MIPI® CSI-2®			







Electronic fuse (eFuse IC) can be used repeatedly to protect circuits from abnormal conditions such as overcurrent and overvoltage.

Can be used repeatedly

When overcurrent flows through the electronic fuse (eFuse IC), the internal detection circuit operates and switches off the internal MOSFET. It is not destroyed by a single overcurrent and can be used repeatedly.

IEC 62368-1 certified

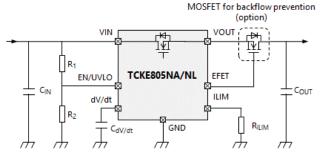
Toshiba's eFuse ICs are certified to the international safety standard IEC 62368-1 (G9: Integrated circuit (IC) current limiters) and contribute to robust protection and simplification of circuit design.

3 Various protection functions

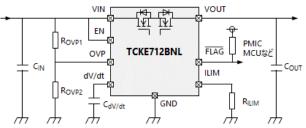
TCKE8 Series: short-circuit protection, overcurrent protection, overcurrent clamp function, overvoltage clamp function, thermal shut down, inrush current suppression, backflow prevention (optional), etc.

TCKE7 Series: short-circuit protection, overcurrent protection, overvoltage protection, thermal shut down, FLAG signal output, backflow prevention (built-in), etc.

Reference circuit example of TCKE8 Series



Reference circuit example of TCKE7 Series



Lineup				
Part number	TCKE800NA/NL	TCKE805NA/NL	TCKE812NA/NL	TCKE712BNL
Package	WSON10B 3.0 x 3.0 x 0.75 mi	m	H. Fred	WSON10 3.0 x 3.0 x 0.75 mm
V _{IN} [V]			4.4 to 13.2	
R _{ON} (Typ.) [mΩ]		53		
Return function	NL: Latch	Latch type (external signal control)		
V _{OVC} (Typ.) [V]	-	6.04	15.1	Adjustable







It is N-ch MOSFET gate driver IC with OVP [Note 1] function. It contributes to reduction of power consumption and miniaturization of load switch circuit.

[Note 1] OVP: Over Voltage Protection

Three types of N-ch MOSFET can be driven

The following types of MOSFET can be driven: TCK40xG: Single high side connection
Common source connection
TCK42xG: Single high side connection
Common drain connection

Wide operating voltage range and various OVLO [Note 2] threshold voltage

Operating voltage V_{opr} : 2.7 to 28 V Maximum input voltage: 40 V V_{IN_OVLO} [Note 3] lineups suitable for 5 to 24V power supply line.

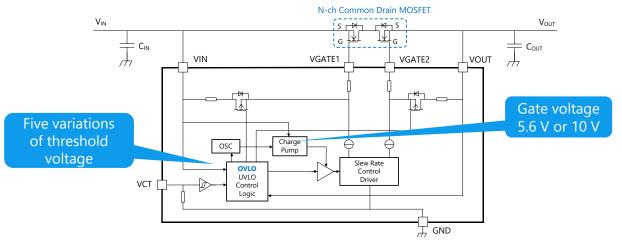
[Note 2] OVLO: Over Voltage Lock Out [Note 3] V_{IN OVLO}: V_{IN} OVLO threshold

3 Small packages

It contributes to reduction of the mounting area and miniaturization of the circuit board:

WCSP6E: 1.2 x 0.8 mm, t: 0.55 mm WCSP6G: 1.2 x 0.8 mm, t: 0.35 mm

Circuit example of TCK42xG with N-ch common drain connection MOSFET



Lineup							
Part number	V _{IN_OVLO} Min / Max [V]	V _{GS} Typ. / Max [V]	N-ch MOSFET type can be driven	Packa	ge		
TCK401G	Over 28	Max 10	Single high side	WCSP6E			
TCK402G	Over 20	(V _{IN} ≥ 12 V)	Common Source	VVC3P6E			
TCK420G	26.50 / 28.50	10 / 11 (V _{IN} ≥ 5 V)	Single high side Common Drain				
TCK421G	22.34 / 24.05						
TCK422G	13.61 / 14.91			MCCDCC			
TCK423G	13.61 / 14.91	5.6 / 6.3		WCSP6G			
TCK424G	10.35 / 11.47						
TCK425G	5.76 / 6.87						

8 Over temperature detection IC (ThermoflaggerTM)







Value provided

TCTH series can detect temperature rise at multiple points on the circuit board.

Temperature rise can be detected at multiple points

TCTH series detect an increase in resistance during over temperature by supplying a constant current (1 μ A or 10 μ A) to PTC (Positive Temperature Coefficient) thermistors. Multiple PTC thermistors connected in series enable to detect over temperature at multiple points on the circuit board.

Example of over temperature detecting circuit by ThermoflaggerTM. thermistor PTC Detection thermistor Detection temperature temperature 120°C Detection 120°C temperature 80°C PTC **Over temperature** thermistor detection IC Thermoflagger[™] 100°C

2 Low current consumption and small package

TCTH01 series has I_{DD} = 1.8 μ A (Typ.) and TCTH02 series has I_{DD} = 11.3 μ A (Typ.). These packages are small size ESV type.

Lineup						
Part number	TCTH011AE/BE	TCTH012AE/BE	TCTH021AE/BE	TCTH022AE/BE		
Package	ESV 1.6 x 1.6 x 0.55 mm					
V _{DD} [V]	1.7 to 5.5					
Ι _{DD} (Typ.) [μΑ]	1.	1.8 11.3				
PTCO Output current (Typ.) [μA]	1	1	10	10		
Abnormal latch function	-	Yes	-	Yes		
Output circuit type		AE: push pull,	BE: open drain			

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